H11B1, H11B2, H11B3

## Optocoupler, Photodarlington Output, High Gain, with Base Connection



## DESCRIPTION

The H11B1, H11B2, H11B3 are industry standard optocouplers, consisting of a gallium arsenide infrared LED and a silicon photodarlington.

FEATURES

- Isolation test voltage: $5300 \mathrm{~V}_{\mathrm{RMS}}$
- Coupling capacitance, 0.5 pF
- Material categorization: For definitions of compliance please see
 www.vishay.com/doc?99912


## AGENCY APPROVALS

- UL1577, file no. E52744 system code J
- DIN EN 60747-5-5 (VDE 0884-5) available with option 1
- FIMKO EN60065, EN60950-1
- CQC: GB8898

| ORDERING INFORMATION |  |  |  |
| :---: | :---: | :---: | :---: |
| PART NUMBER |  | PACKAGE OPTION |  |
| AGENCY CERTIFIED/PACKAGE | CTR (\%) |  |  |
| UL, FIMKO, CQC | > 500 | > 200 | > 100 |
| DIP-6 | H11B1 | H11B2 | H11B3 |
| SMD-6, option 7 | H11B1-X007T ${ }^{(1)}$ | - | - |
| SMD-6, option 9 | H11B1-X009 | H11B2-X009T ${ }^{(1)}$ | - |
| UL, FIMKO, CQC, VDE | > 500 | > 200 | > 100 |
| SMD-6, option 7 | H11B1-X017 | - | - |

Notes

- Additional options may be possible, please contact sales office.
${ }^{(1)}$ Also available in tubes, no " $T$ " in the end.

| ABSOLUTE MAXIMUM RATINGS ( $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$, unless otherwise specified) |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT |
| INPUT |  |  |  |  |
| Reverse voltage |  | $\mathrm{V}_{\mathrm{R}}$ | 3 | V |
| Forward continuous current |  | $\mathrm{I}_{\mathrm{F}}$ | 60 | mA |
| Power dissipation |  | $\mathrm{P}_{\text {diss }}$ | 100 | mW |
| Derate linearly from $25^{\circ} \mathrm{C}$ |  |  | 1.33 | $\mathrm{mW} /{ }^{\circ} \mathrm{C}$ |
| OUTPUT |  |  |  |  |
| Collector emitter breakdown voltage |  | $\mathrm{BV}_{\text {CEO }}$ | 25 | V |
| Emitter collector breakdown voltage |  | $\mathrm{BV}_{\text {ECO }}$ | 7 | V |
| Collector base breakdown voltage |  | $\mathrm{BV}_{\text {CBO }}$ | 30 | V |
| Collector current (continuous) |  | $\mathrm{I}_{\mathrm{C}}$ | 100 | mA |
| Power dissipation |  | $\mathrm{P}_{\text {diss }}$ | 150 | mW |
| Derate linearly from $25^{\circ} \mathrm{C}$ |  |  | 2 | $\mathrm{mW} /{ }^{\circ} \mathrm{C}$ |

H11B1, H11B2, H11B3
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| ABSOLUTE MAXIMUM RATINGS ( $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$, unless otherwise specified) |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT |
| COUPLER |  |  |  |  |
| Isolation test voltage between emitter and detector |  | VISO | 5300 | $\mathrm{V}_{\text {RMS }}$ |
| Creepage distance |  |  | $\geq 7$ | mm |
| Clearance distance |  |  | $\geq 7$ | mm |
| Comparative tracking index per DIN IEC 112/VDE 0303, part 1 |  | CTI | 175 |  |
| Isolation resistance | $\mathrm{V}_{\text {IO }}=500 \mathrm{~V}, \mathrm{~T}_{\text {amb }}=25^{\circ} \mathrm{C}$ | $\mathrm{R}_{10}$ | $\geq 10^{12}$ | $\Omega$ |
|  | $\mathrm{V}_{1 \mathrm{O}}=500 \mathrm{~V}, \mathrm{~T}_{\mathrm{amb}}=100^{\circ} \mathrm{C}$ | $\mathrm{R}_{\mathrm{IO}}$ | $\geq 10^{11}$ | $\Omega$ |
| Total package dissipation (LED plus detector) |  | $\mathrm{P}_{\text {tot }}$ | 260 | mW |
| Derate linearly from $25^{\circ} \mathrm{C}$ |  |  | 3.5 | $\mathrm{mW} /{ }^{\circ} \mathrm{C}$ |
| Storage temperature |  | $\mathrm{T}_{\text {stg }}$ | -55 to +150 | ${ }^{\circ} \mathrm{C}$ |
| Operating temperature |  | $\mathrm{T}_{\text {amb }}$ | -55 to + 100 | ${ }^{\circ} \mathrm{C}$ |
| Lead soldering time at $260{ }^{\circ} \mathrm{C}$ |  |  | 10 | s |

## Note

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

ELECTRICAL CHARACTERISTICS ( $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$, unless otherwise specified)

| PARAMETER | TEST CONDITION | PART | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| INPUT |  |  |  |  |  |  |  |
| Forward voltage | $\mathrm{I}_{\mathrm{F}}=50 \mathrm{~mA}$ | H11B1 | $V_{\text {F }}$ |  | 1.1 | 1.5 | V |
|  |  | H11B2 | $\mathrm{V}_{\mathrm{F}}$ |  | 1.1 | 1.5 | V |
|  | $\mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA}$ | H11B3 | $\mathrm{V}_{\mathrm{F}}$ |  | 1.1 | 1.5 | V |
| Reverse current | $\mathrm{V}_{\mathrm{R}}=3 \mathrm{~V}$ |  | $\mathrm{I}_{\mathrm{R}}$ |  |  | 10 | $\mu \mathrm{A}$ |
| Junction capacitance | $\mathrm{V}_{\mathrm{F}}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |  | $\mathrm{C}_{\mathrm{j}}$ |  | 50 |  | pF |
| OUTPUT |  |  |  |  |  |  |  |
| Collector emitter breakdown voltage | $\mathrm{I}_{\mathrm{C}}=1 \mathrm{~mA}, \mathrm{I}_{\mathrm{F}}=0 \mathrm{~mA}$ |  | $\mathrm{BV}_{\text {CEO }}$ | 30 |  |  | V |
| Emitter collector breakdown voltage | $\mathrm{I}_{\mathrm{E}}=100 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{F}}=0 \mathrm{~mA}$ |  | $\mathrm{BV}_{\mathrm{ECO}}$ | 7 |  |  | V |
| Collector base breakdown voltage | $\mathrm{I}_{\mathrm{C}}=100 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{F}}=0 \mathrm{~mA}$ |  | $\mathrm{BV}_{\text {CBO }}$ | 30 |  |  | V |
| Collector emitter leakage current | $\mathrm{V}_{\mathrm{CE}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=0 \mathrm{~mA}$ |  | $\mathrm{I}_{\text {CEO }}$ |  |  | 100 | nA |
| COUPLER |  |  |  |  |  |  |  |
| Saturation voltage collector-emitter | $\mathrm{I}_{\mathrm{F}}=1 \mathrm{~mA}, \mathrm{I}_{\mathrm{C}}=1 \mathrm{~mA}$ |  | $\mathrm{V}_{\text {cEsat }}$ |  |  | 1 | V |
| Capacitance (input to output) |  |  | $\mathrm{C}_{10}$ |  | 0.5 |  | pF |

## Note

- Minimum and maximum values were tested requierements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO ( $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$, unless otherwise specified)

| PARAMETER | TEST CONDITION | PART | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| DC current transfer ratio | $\mathrm{V}_{\mathrm{CE}}=5 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=1 \mathrm{~mA}$ | H 11 B 1 | $\mathrm{CTR}_{\mathrm{DC}}$ | 500 |  |  | $\%$ |
|  |  | H 11 B 2 | $\mathrm{CTR}_{\mathrm{DC}}$ | 200 |  |  | $\%$ |
|  |  | H 11 B 3 | $\mathrm{CTR}_{\mathrm{DC}}$ | 100 |  |  |  |


| SWITCHING CHARACTERISTICS $\left(\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}\right.$, unless otherwise specified $)$ |  |  |  |  |  |  |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: |
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| Switching times | $\mathrm{I}_{\mathrm{F}}=5 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=10 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=100 \Omega$ | $\mathrm{t}_{\mathrm{on}}$ |  | 5 |  | $\mu \mathrm{~s}$ |
|  |  | $\mathrm{t}_{\mathrm{fff}}$ |  | 30 |  | $\mu \mathrm{~s}$ |

TYPICAL CHARACTERISTICS $\left(\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}\right.$, unless otherwise specified)


Fig. 1 - Forward Voltage vs. Forward Current


Fig. 2 - Normalized Non-Saturated and Saturated CTR CE vs. LED Current


Fig. 3 - Normalized Non-Saturated and Saturated $\mathrm{I}_{\mathrm{CE}}$ vs. LED Current


Fig. 4 - Normalized Non-Saturated and Saturated Collector Emitter Current vs. LED Current


Fig. 5 - Non-Saturated and Saturated h he vs. Base Current


Fig. 6 - Low to High Propagation Delay vs. Collector Load Resistance and LED Current


Fig. 7 - High to Low Propagation Delay vs. Collector Load Resistance and LED Current

ih11b1_08

Fig. 8 - Switching Waveform


Fig. 9 - Switching Schematic

PACKAGE DIMENSIONS in millimeters


ISO method A


Option 7



## PACKAGE MARKING



## Notes

- Only options 1, 7, and 9 are reflected in the package marking.
- The VDE logo is only marked on option 1 parts.
- Tape and reel suffix $(T)$ is not part of the package marking.


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